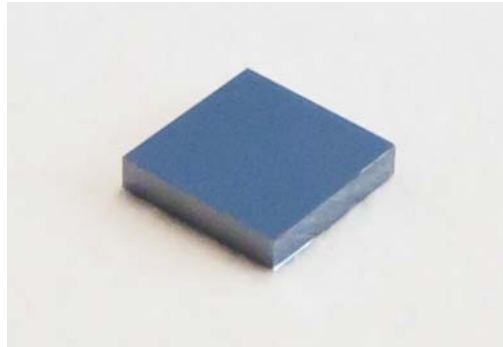


B-M-1030nm-4x4**Bragg mirror 1030 nm with chip area 4.0 mm x 4.0 mm on GaAs**

Material:	AlAs/GaAs epitaxial Bragg mirror on single crystalline GaAs substrate
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm

Spectral reflectance